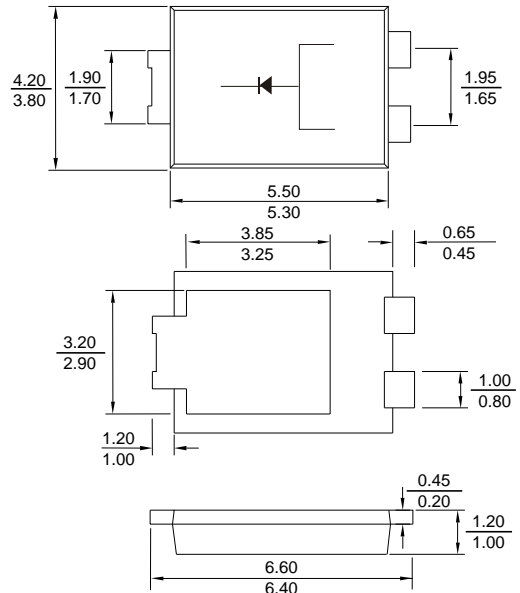


Features

- Bypass Diodes for Solar Panels
- High Junction Temperature
- High Thermal Reliability
- Patented Super Barrier Rectifier Technology
- High Forward Surge Capability
- Ultra Low Power Loss, High Efficiency
- Excellent High Temperature Stability



TO-277B



Mechanical Data

- Case: TO-277B Molded Plastic "Green" Molding Compound
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.093 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Lead Free: For RoHS/Lead Free Version

Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| Characteristic | Symbol | SR2045L | Unit |
|---|-----------------|-----------------------------------|---------------------------|
| Peak Repetitive Reverse Voltage | V_{RRM} | 45 | V |
| Working Peak Reverse Voltage | V_{RWM} | | |
| DC Blocking Voltage | V_R | | |
| RMS Reverse Voltage | $V_{R(RMS)}$ | 32 | V |
| Average Rectified Output Current (Note 1) @ $T_L = 90^\circ\text{C}$ | I_o | 20.0 | A |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 275 | A |
| Forward Voltage Drop @ $I_F = 5\text{A}, T_J = 25^\circ\text{C}$ @ $I_F = 20\text{A}, T_J = 25^\circ\text{C}$ | V_{FM} | Typ. 0.40 Typ. - 0.485 0.63 | V |
| Peak Reverse Current At Rated DC Blocking Voltage $T_J = 25^\circ\text{C}$ $T_J = 100^\circ\text{C}$ | I_R | 0.3 10 | mA |
| Repetitive Peak Avalanche Power(1us,25°C) | P_{ARM} | 30000 | W |
| Typical Thermal Resistance Junction to Ambient (Note 2) (Note 3) | $R_{\theta JA}$ | 70 15 | $^\circ\text{C}/\text{W}$ |
| Operating Temperature Range @ $V_R \leq 80\% V_{RRM}$ | T_J | -55 to +150 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{STG} | -55 to +150 | $^\circ\text{C}$ |

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. FR-4 PCB, 2oz. Copper, minimum recommended pad layout .

3. Polyimide PCB, 2oz. Copper. Cathode pad dimensions 18.8mm x 14.4mm. Anode pad dimensions 5.6mm x 14.4mm.

FIG.1 - FORWARD CURRENT DERATING CURVE

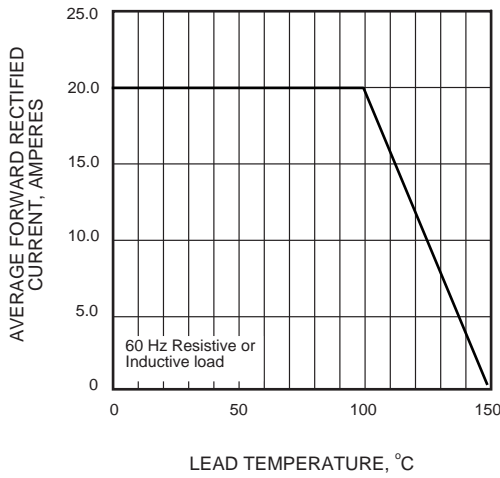


FIG.2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

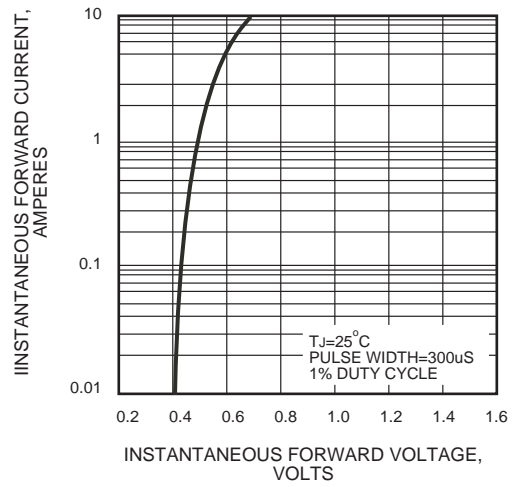


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

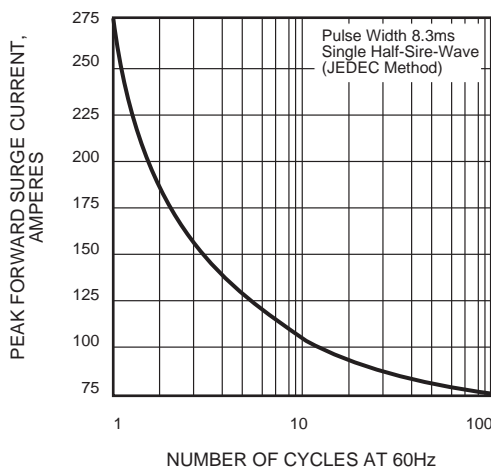


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

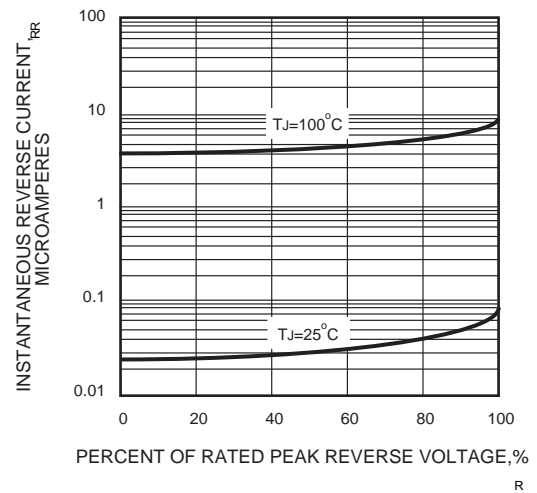


FIG.5 - TYPICAL JUNCTION CAPACITANCE

